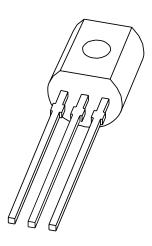
DISCRETE SEMICONDUCTORS

DATA SHEET



2N5550; 2N5551 NPN high-voltage transistors

Product specification Supersedes data of 1999 Apr 23 2004 Oct 28





NPN high-voltage transistors

2N5550; 2N5551

FEATURES

- Low current (max. 300 mA)
- High voltage (max. 160 V).

APPLICATIONS

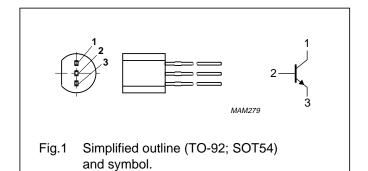
 Switching and amplification in high voltage applications such as telephony.

DESCRIPTION

NPN high-voltage transistor in a TO-92; SOT54 plastic package. PNP complements: 2N5400 and 2N5401.

PINNING

PIN	DESCRIPTION
1	collector
2	base
3	emitter



ORDERING INFORMATION

TYPE NUMBER		PACKAGE		
TIPE NOWIBER	NAME DESCRIPTION			
2N5550	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54	
2N5551				

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter			
	2N5550		_	160	V
	2N5551		_	180	V
V _{CEO}	collector-emitter voltage	open base			
	2N5550		_	140	V
	2N5551		_	160	V
V _{EBO}	emitter-base voltage	open collector	_	6	V
I _C	collector current (DC)		_	300	mA
I _{CM}	peak collector current		_	600	mA
I _{BM}	peak base current		_	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	_	630	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	ambient temperature		-65	+150	°C

NPN high-voltage transistors

2N5550; 2N5551

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	200	K/W

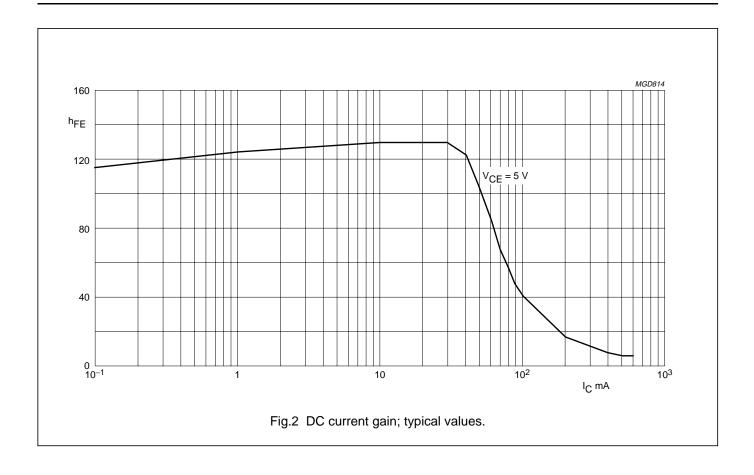
CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{CBO}	collector-base cut-off current				
	2N5550	V _{CB} = 100 V; I _E = 0 A	_	100	nA
		V _{CB} = 100 V; I _E = 0 A; T _j = 100 °C	_	100	μΑ
	collector-base cut-off current				
	2N5551	$V_{CB} = 120 \text{ V}; I_E = 0 \text{ A}$	_	50	nA
		V _{CB} = 120 V; I _E = 0 A; T _j = 100 °C	_	50	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 4 V; I _C = 0 A	_	50	nA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 1 \text{ mA}; \text{ see Fig.2}$			
	2N5550		60	_	
	2N5551		80	_	
	DC current gain	V _{CE} = 5 V; I _C = 10 mA; see Fig.2			
	2N5550		60	250	
	2N5551		80	250	
	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 50 \text{ mA}; \text{ see Fig.2}$			
	2N5550		20	_	
	2N5551		30	_	
V _{CEsat}	collector-emitter saturation voltage	I _C = 10 mA; I _B = 1 mA			
	2N5550		_	150	mV
	2N5551		_	150	mV
	collector-emitter saturation voltage	$I_C = 50 \text{ mA}; I_B = 5 \text{ mA}$			
	2N5550		_	250	mV
	2N5551		_	200	mV
V _{BEsat}	base-emitter saturation voltage	I _C = 10 mA; I _B = 1 mA	_	1	V
		I _C = 50 mA; I _B = 5 mA	_	1	V
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$	_	6	pF
C _e	emitter capacitance	$V_{EB} = 0.5 \text{ V}; I_C = i_c = 0 \text{ A}; f = 1 \text{ MHz}$	_	30	pF
f _T	transition frequency	$V_{CE} = 10 \text{ V}; I_{C} = 10 \text{ mA}; f = 100 \text{ MHz}$	100	300	MHz
F	noise figure	$V_{CE} = 5 \text{ V}; I_{C} = 200 \mu\text{A}; R_{S} = 2 \text{k}\Omega;$			
	2N5550	f = 10 Hz to 15.7 kHz	_	10	dB
	2N5551		_	8	dB

NPN high-voltage transistors

2N5550; 2N5551



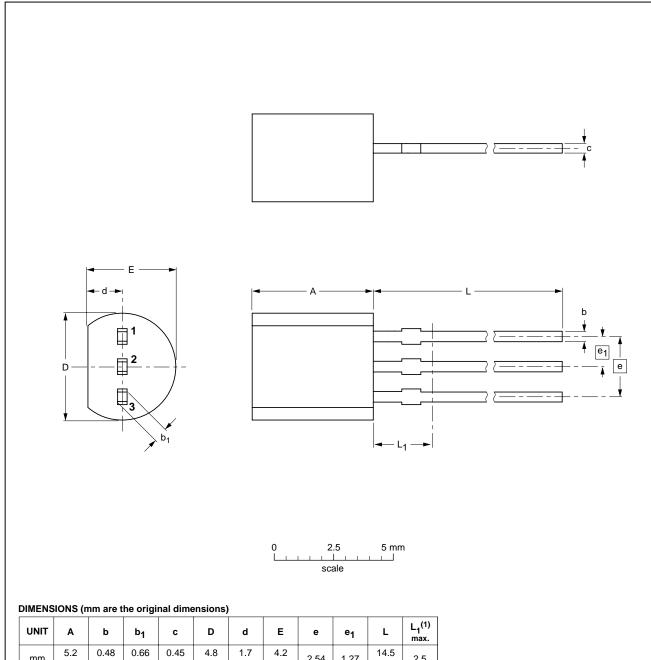
NPN high-voltage transistors

2N5550; 2N5551

PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



UNIT	Α	b	b ₁	С	D	d	E	е	e ₁	L	L ₁ ⁽¹⁾ max.
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT54		TO-92	SC-43A		97-02-28 04-06-28

5 2004 Oct 28

NPN high-voltage transistors

2N5550; 2N5551

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

DISCLAIMERS

Life support applications — These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes in the products - including circuits, standard cells, and/or software - described or contained herein in order to improve design and/or performance. When the product is in full production (status 'Production'), relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN). Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

Philips Semiconductors – a worldwide company

Contact information

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

© Koninklijke Philips Electronics N.V. 2004

SCA76

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

Printed in The Netherlands

R75/04/pp7

Date of release: 2004 Oct 28

Document order number: 9397 750 13548

Let's make things better.



